SPECIFICATION

191

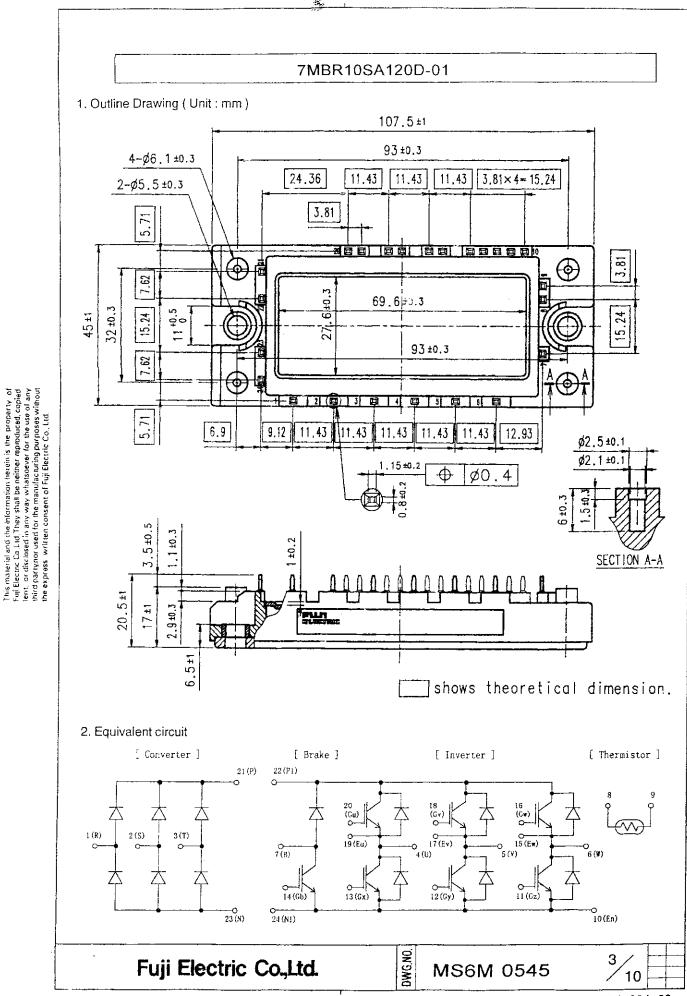
	Device Name) <u>:</u>	IGBT Module
	Type Name		7MBR10SA120D-01
	Spec. No.	:	MS6M 0545
	Date	:	Jun 02 - 2000
			-
			Fuji Electric Co.,Ltd. Matsumoto Factory
DATE DRAWN Jun - Z - 60	NAME APPR	OVED	Fuji Electric Co.,Ltd.
CHECKED June - 2 - 00)		asta	MS6M 0545 1/10
			H04-004-05

This material and the information herein is the property of Full Election Co. Ltd. They shall be neither reproduced, copied lent, or disclosed in any way whatsever for the use of any third partynor used for the manufacturing purposes without the express written consent of Full Electric Co., Ltd.

Revised Records

Date	Classi- fication	Ind.	Content	Applied date	Drawn	Checked	Approved
Jun - 2 - 60	enactment			lssued date		N; Melta	Trivanda
				-			
						-	
I		ı <u></u>			<u>.</u>	<u>, , , , , , , , , , , , , , , , , , , </u>	1
	⁻ uji Elec			ON 9MG MS	<u></u>	<u>_</u>	² /10

This material and the Information berein is the property of Fuji Electine Co. Ltd. Thoy shall be neither reproduced, copied tent, or disclosed in any way whatsoever for the use of any third partynor used for the manufacturing purposes without the express written consent of Fuji Electric Co. Ltd



		ltems	Symbols	Condit	ions	Maximum Ratings	U
	Collec	tor-Emitter voltage	VCES	···· —		1200	┢
	Gate-	Emitter voltage	VGES			+-20	+
			lc	Continuous	Tc=25C	15	1
er					Tc=80C	10	-
Inverter	Collec	tor current	lcp	1ms	Tc=25C	30	+
<u> </u>					Tc=80C	20	1
I			-lc			10	+
	Collec	tor Power Dissipation	Pc	1 dev	ice	75	+
	Collec	tor-Emitter voltage	VCES			1200	┢
	Gate-I	Emitter voltage	VGES			+-20	┢
			lc	Continuous	Tc=25C	15	+-
an.	Collec	tor current			Tc=80C	10	-
Brake	1		lcp	1ms	Tc=25C	30	+
Ω			- P	inic	Tc=80C	20	-
	Collec	tor Power Dissipation	Pc	1 devi		┼╼	
	Repetitive peak reverse Voltage(Diode)					1200	+
	Repetitive peak reverse Voltage		VRRM			1600	+
D				50Hz/60Hz			
vert	Average Output Current		lo	sine wave		25	
Converter	Surge Current (Non-Repetitive)		IFSM	Tj=150C,10ms		260	╞
0	I ² t (Non-Repetitive)		² t	half sine wave		338	1
Junc	tion ter	nperature				150	
Stor	age ten	perature	Tstg			-40~ +125	<u>+</u>
sola	ition	between terminal and copper base(*1)	Viso	AC : 1r	2500		
volta	age	between thermistor and others (*2)			ŀ	2500	┢
Mou	nting S	crew Torque (*3)				3.5	+
	sho	minal 8 and 9 should be connected toge buld be connected together and shorted t ecommendable Value : 2.5~3.5 Nm (M	o copper base.				

3. Absolute Maximum Ratings (at Tc= 25C unless otherwise specified)

This material and the information berein is the property of Full Electric Co. Ltd. They shall be neither reproduced, copied, lent, or disclosed in any way whatsoever for the use of any third partynor used for the manufacturing purposes without the express written consent of Fuji Electric Co., Ltd.

			[Cha	aracteris	tics	Τ	
	Items	Symbols	Cone	ditions	min.	typ.	Max.	1
	Zero gate voltage Collector current	ICES		VCE 1200 V			1.0	
	Gate-Emitter leakage current	IGES	VCE OV,	VGE +-20 V			200	1
Inverter	Gate-Emitter threshold voltage	VGE(th)	VCE 20 V,	lc = 10 mA	5.5	7.2	8.5	
	Collector-Emitter	VCE(sat)	VGE 15 V,	chip		2.1		T
	saturation voltage		lc = 10 A	terminal		2.15	2.6	1
	Input capacitance	Cies	VGE 0 V, f = 1 M	VCE 10 V Hz		1200		
	Turn-on time	ton	Vcc= 600 V			0.35	1.2	╉
		tr	lc≕ 10 A			0.25	0.6	
		tr _(i)	VGE +-15 V			0.1		1
	Turn-off time	toff	RG = 120 of	m		0.45	1.0	٦
		tf	-			0.08	0.3	1
	Forward on voltage	VF	IF = 10 A	chip		2.3		1
				terminal		2.35	3.2	1
	Reverse recovery time	trr	IF = 10 A			. <u> </u>	350	1
	Zero gate voltage Collector current	ICES	VGE 0 V	VCE 1200 V			1.0	
	Gate-Emitter leakage current	IGES	VCE 0 V	, VGE +-20 V			200	1
	Collector-Emitter	VCE(sat)	VGE 15 V	, chip	1	2.1		
	saturation voltage			terminal	•	2.2	2.6	
Brake	Turn-on time	ton	Vcc= 600 V			0.35	1.2	Ţ
B		tr	lc= 10 A			0.25	0.6	
	Turn-off time	toff	VGE +-15 V			0.45	1.0	Ţ
		tf	RG = 120 of	nm		0.08	0.3	
	Reverse current	İRRM	VR = 1200 V	······································			1.0	
fer	Forward on voltage	VFM	IF = 10 A	chip		0.9		Ī
Converter				terminal		1.0	1.5	
Õ	Reverse current	IRRM	VR = 1600 V				1.0	Τ
<u>n</u>	Resistance	R	T = 25C			5000	1	T
mist			T=100C		465	495	520]
Thermistor	B value	В	T = 25/50C		3305	3375	3450	
		t						_

This material and the information herein is the property of Fuji Elector Co. Ltd. They shall be neither reproduced, copied leon, or disclosed in any way whatsoever for the use of any third partypror used for the manufacturing purposes without the express written consent of Fuji Electric Co.. Ltd.

5. Thermal resistance characteristics

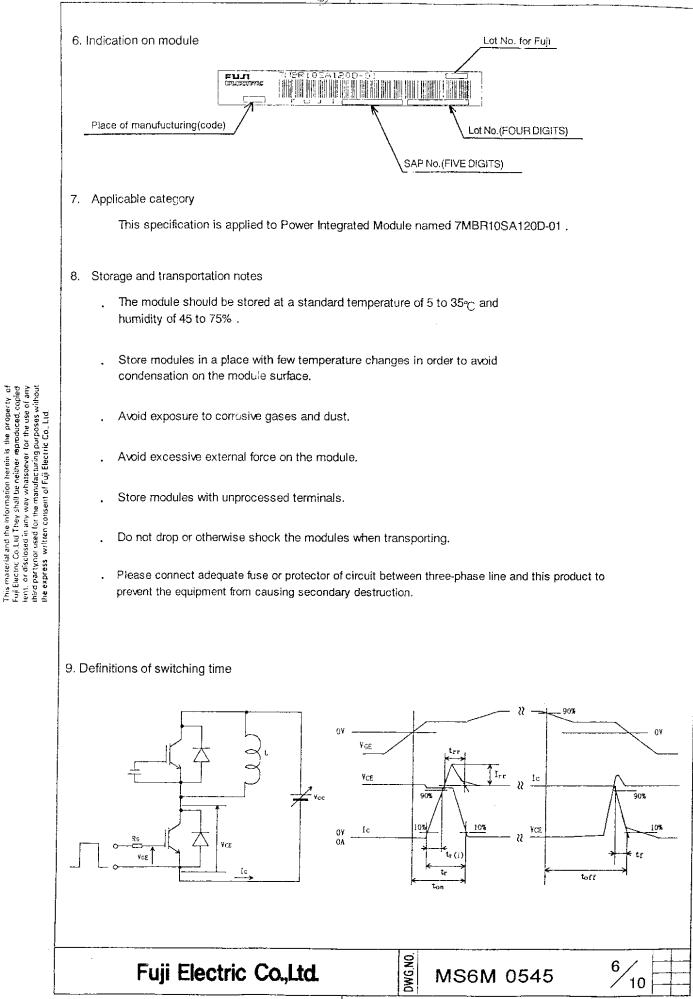
		[Characteristics					
Items	Symbols	Conditions	min.	týp.	Max.	Units		
		Inverter IGBT			1.67			
Thermal resistance	Rth(j-c)	Inverter FWD			2.78	c/w		
(1 device)		Brake IGBT			1.67	1		
		Converter Diode			1.30	1		
Contact Thermal resistance	Rth (c-f)	with Thermal Compound (*)	┪	0.05		C/W		

DWG.NO.

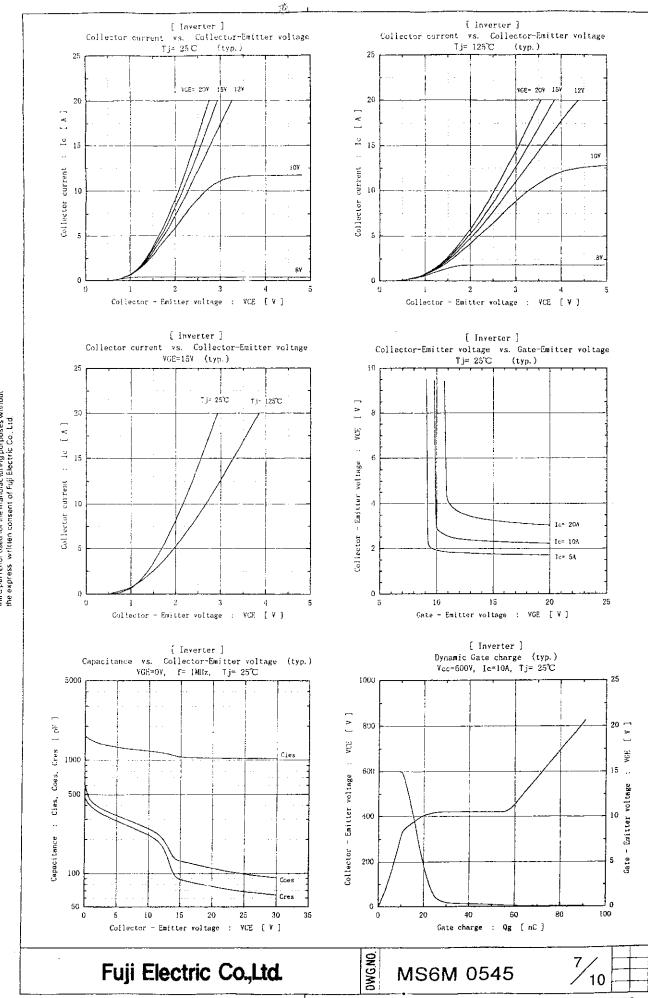
Fuji Electric Co.,Ltd.

MS6M 0545

5

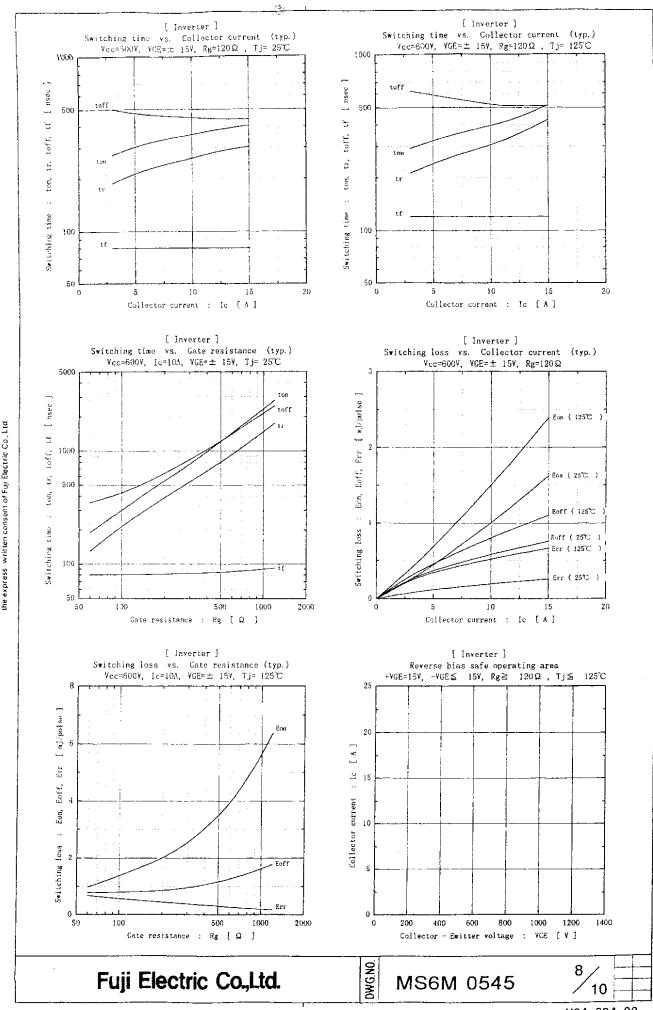


H04-004-03



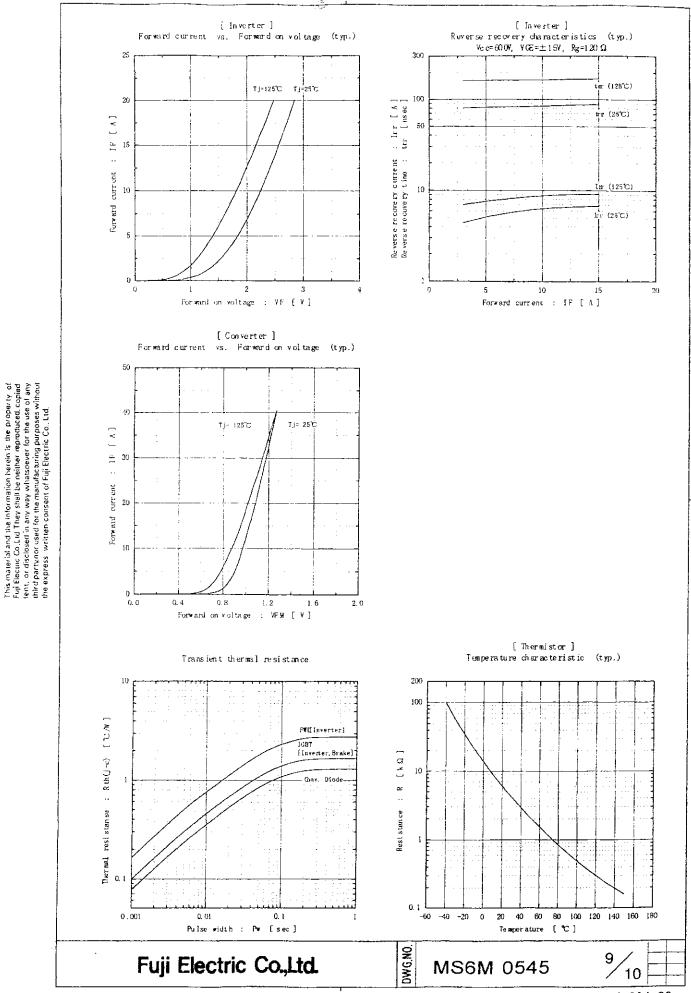
This material and the Information herein is the property of Full Electric Co. Ltd. They shall be neither reproduced, copied tent. or disclosed in any way whatseover for the use of any third partynor used for the manufacturing purposes without the express written consent of Full Electric Co. Ltd.

H04-004-03

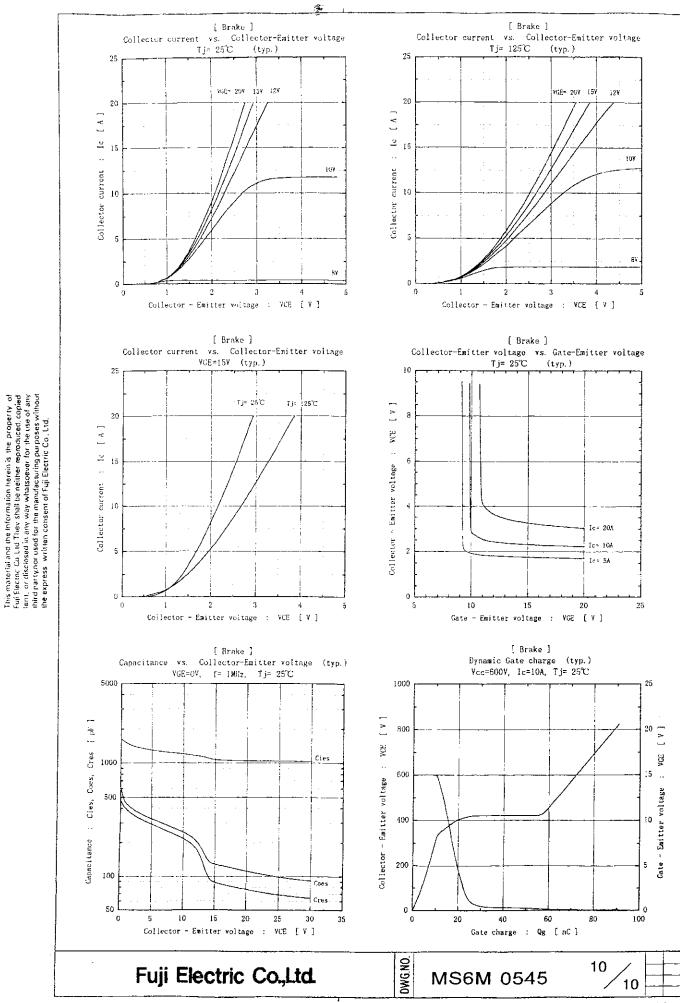


This material and the Information herein is the property of Fuil Electric Co. Ltd. They shall be neither reproduced, copied tent, or disclased in any way whatsoever for the use of any third partynor used for the manufacturing purposes without the express written consent of Fuil Electric Co., Ltd

H04-004-03



H04~004-03



H04-004-03